

Theory of Operation

System/360 Model 50
Capacitor Read Only Storage

## PREFACE

This manual describes the theory of microprogramming, logic, and the operation of Capacitor Read Only Storage in the 2050 Processing Unit.

The reader should have a basic knowledge of the data flow paths and functional units of the 2050 Processing Unit.

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This manual, Form Y22-2823-0 obseletes Form 222-2823-2 and 222-2823-1. Except for the removal of the IBM Confidential classification, this manual is identical to Form Z22-2823-2. Changes are periodically made to the specifications herein; any such changes will be reported in subsequent revisions or FE Supplements.

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- IBM System/360 Model 50 is controlled by a microprogram.
- A microprogram word controls each machine cycle.
- System control lines and gates are controlled by fields in the microprogram word.
- Capacitor Read Only Storage (CROS) contains the microprogram.
- CROS contains 2816, 90 bit words.
- Bit patterns of CROS words are determined by the presence or absence of capacitors.
- CROS words can be changed by replacing printed circuit sheets.


## Microprogram

Capacitor Read Only Storage (CROS) is the storage device that contains the IBM System/360 Model 50 microprogram. The microprogram is stored in 2816 words of 90 bits each. Each 90 -bit word controls the gates and control lines of the system for one 500 ns machine cycle; gating for each functional unit is controlled by the bit combination within a field of the microprogram word. For example, 001 in bit positions $65-67$ of the microprogram word gates the $R$ register to the right adder input.

Figure 1 shows the relationship of CROS to the system clock and control lines; only the clock can operate independently of the microprogram words from CROS.

## CROS

Capacitor Read Only Storage is a storage device for predetermined information that can be nondestructively read out. The bit pattern of a CROS word is determined by the presence or absence of capacitors within the CROS hardware; a CROS word cannot be changed by customer programs. However, the Customer Engineer can change the information in the CROS words by replacing printed circuit sheets. Capacitor Read Only Storage replaces most of the system control circuits and introduces a flexibility to machine design not previously available in control hardware. This flexibility allows making control circuit changes for a special feature by replacing printed circuit sheets in CROS.

## CROS ELECTRICAL THEORY

- A capacitor represents a bit of information.
- One drive line drives the capacitors for one CROS word.
- Capacitors couple the drive lines to sense lines.
- There is one sense amplifier for each bit position of the CROS word.
- Sense amplifier outputs are stored in Read Only Storage Data Registers (ROSDR).
- Drive lines are selected by decoding a Read Only Address Register (ROAR).

Drive and Sense Lines
Capacitor Read Only Storage uses a capacitor between drive and sense lines to represent a bit of information. Figure 2 shows a basic capacitor storage matrix. Only one driver at a time may be active. If driver 1 is made active, the voltage shift on the drive line is capacity-coupled to the A-sense line. The sense amplifier amplifies the voltage shift and produces an A-bit output. If driver 3 is made active, the drive line voltage shift is capacity-coupled to the B and D sense lines, producing a B-bit and a D-bit output.

Some unwanted capacitive coupling exists in a capacitor storage matrix of this type. When driver 1 is made active, capacitor C1 couples the voltage shift to the A-sense line, capacitor C2 couples the voltage shift on the A-sense line to the driver 2 drive line, and capacitor C 3 couples the voltage shift from the driver 2 drive line to the C-sense line. Because any unwanted signal must pass through at least three elements in cascade, the unwanted signal will be greatly decreased. The threshold of the sense amplifier is such that the desired signal is amplified while the unwanted, weakened signal is rejected.

## Differential Sense Amplifiers

To further reduce unwanted signals and noise, each sense line is divided into a pair of sense lines which feed a differential amplifier that amplifies the difference between the two input lines. Each drive line is capacitor-coupled to one line of each pair of sense lines (Figure 3). A capacitor that causes a positive output from the differential sense amplifier represents


FIGURE 1. CROS DATA FLOW


FIGURE 2. BASIC CAPACITOR MATRIX
a zero bit, while a capacitor that causes a negative output represents a one bit. Thus, each drive line has the same capacitive load regardless of the bit configuration.

## Balance Lines

An extra line, called a balance line, is added for each drive line. The balance line is not connected to a driver; instead, it is connected to the drive line voltage source at one end and allowed to float at the other end. A capacitor is connected from the balance line to whichever sense line is not connected to the drive line. Thus, each sense line has the same capacitive load regardless of the bit configuration.

## Data Register

The Read Only Storage Data Register (ROSDR) stores the sense amplifier outputs (Figure 4). ROSDR holds the CROS word available to the decode circuits for one machine cycle.

## Address Register

The Read Only Address Register (ROAR) stores the address of the next CROS word. The address in ROAR is decoded to select one CROS driver. The address sent to ROAR is controlled by the CROS word for the machine cycle being executed.

## THEORY OF MICROPROGRAMMING

- The processing unit is controlled by microprogram words.
- Microprogram words are grouped into routines.
- Microprogram routines control processing of customer program instructions.
- Each machine cycle is controlled by a microprogram word.

Microprogramming is the use of internal program words, built into the machine, that control the gates and control lines during each machine cycle. For example, a customer program instruction of Add RR Format is decoded to cause CROS to read out the first word of a microprogram routine. The microprogram routine fetches general purpose registers R1 and R2 from local storage, adds them together, and stores the answer in R1. Each machine cycle necessary for the operation is controlled by a microprogram word.

## Microprogram Word

- Each microprogram word controls the address of the next microprogram word.
- Fields within the microprogram word control data flow gates and control lines.

The microprogram word is the set of bits read out of CROS and stored in the Read Only Storage Data Register (ROSDR). Figure 5 shows the breakdown of the microprogram word.

Control Fields: The microprogram word is divided into control fields that control the data flow gates in the computer and the addressing of the next CROS word.

Micro-Orders: A micro-order represents a specific bit combination within a control field. A microorder is decoded into one or more control lines or gates. Micro-orders are written as a symbolic representation of the control lines or gates that result from decoding the control field. For example, the micro-order that gates the $T$ latches to the A register has the symbolic representation $\mathrm{T} \rightarrow$ A.

## Controlling Data Flow With Microprogramming

Figure 6 shows a multiply operation on a fictitious CROS-controlled computer. Assume that the cus-tomer-program instruction to multiply register $A$ times register $B$ and store the product in register $C$ has been decoded and has addressed CROS word 0000, the start of the multiply routine. Each CROS word controls the data flow for one machine cycle as follows:

0000 Zeros are sent through the adder and stored in register C. CROS word 1100 is addressed.

1100 Register A is sent through the adder and checked for all zeros. If register $A$ is all zeros, the multiply operation is over and the branch on zero test causes CROS word 0011 to be addressed. If register $A$ is not zero CROS word 0010 is addressed.

0010 Register B and register C are added together and stored in register C. CROS word 0100 is addressed.

0100 Register A is reduced by one by adding register A to complemented zeros with a no carry insert. If the result is zero, the multiply


FIGURE 3. BASIC $4 \times 4$ CROS MATRIX


FIGURE 4. BASIC CROS


FIGURE 5. MICROPROGRAM WORD FOR A FICTITIOUS COMPUTER

operation is over and CROS word 0011 is addressed. If the result is not zero CROS word 0010 is addressed.

0011 This word starts the routine to decode the next customer-program instruction.


## CHAPTER II. FUNCTIONAL UNITS

- A 12-position address register (ROAR) controls which CROS word is read out.
- ROAR positions 5-9 control the select lines..
- ROAR positions 0-4 and A control the drive lines.
- Select and drive lines control the array drivers.
- Array drivers read two CROS words, at the same time, to the sense amplifiers.
- ROAR position B gates one of the two CROS words to the ROS latches.
- ROS latches hold the CROS word available to the ROSDR latches.
- ROSDR latches hold the CROS word available to the parity and decode circuits.
- Decode circuits decode the CROS word into control lines and gates.
- Parity circuits check the CROS word for missing or extra bits.

Figure 7 shows the CROS functional units and their relationship to each other.

## CROS PLANES

- CROS is divided into 16 planes.
- Planes 0-7 are on gate C.
- Planes 8-15 are on gate D.
- Each plane contains 176 CROS words.
- Each CROS word contains 90 bits.

The 2,816 words of CROS are stored in 16 planes. Figure 8 shows the location of the planes on gates $C$ and D. Each plane contains the capacitors, drive lines, balance lines, and sense lines for 176, 90-bit CROS words.

Each plane contains independent drive and balance lines, while the sense lines for all planes feed common sense amplifiers.

## Drive and Balance Lines (Bit Plates)

- Drive and balance lines are photo-etched onto replaceable printed circuit sheets (bit plates).


FIGURE 8. CROS PLANE LOCATIONS - TOP VIEW

- The drive and balance lines, a sheet of dielectric, and the sense lines form the bit capacitors.
- The shape of the drive and balance lines form the bit configuration for each bit plate.
- The CROS bit configuration can be changed by replacing bit plates.

The drive and balance lines are photo-etched from a sheet of copper that is bonded to epoxy glass (Figure 9). The resulting epoxy sheet with copper drive and balance lines is called a bit plate. A separate bit plate controls the bit configuration for each CROS plane.

Tabs at the top and bottom of the bit plate are used for electrical connections to the drive and balance lines. The top tabs connect the drive and balance lines to terminating resistors. The bottom tabs connect the drive lines to the driver circuits.

The four holes in the bit plate are used to align the bit plane over the sense plane. Two holes snap over locating studs in the plane, while the other two holes provide clearance for the center studs.

## Bit Capacitors

The bit capacitors are formed by sandwiching a sheet of Mylar* between the bit plate and sense lines (Figure 10). Pressure plates hold these pieces firmly together. The Mylar is the dielectric, while the drive, balance, and sense lines become the plates of the capacitors.

Protrusions of the drive and balance lines increase the size of the capacitors to form the bit configuration. The effective capacitor coupling of a drive line to a sense amplifier is equal to C 1 minus

* Trademark of E.I. duPont deNemours \& Co. (Inc.)


Note: Each number on the left side refers to a pair of lines.

FIGURE 9. BIT PLATE


FIGURE 10. BIT CAPACITORS

C2. The size of this effective capacitor is approximately 0.5 picofarads.

The bit configuration within a CROS plane is controlled by the bit plate. Therefore, the microprogram instruction in a CROS word can be changed by replacing the bit plate that contains the word.

## Sense Lines

- There are 400 sense lines in each CROS sense plane.
- A pair of sense lines carry the signal for one CROS-word-bit position.
- 360 sense lines read out two 90-bit CROS words simultaneously.
- The lower 40 sense lines are not used.

The sense lines are photo-etched into copper covered epoxy-glass plates (Figure 11). The sense-line plates are permanently mounted to the array gates. Electrical connections from the sense lines to the terminating resistors and sense amplifiers are made with low temperature solder.

There are 400 sense lines in each CROS plane. Two sense lines are required to read out one bit position of the CROS word. One drive line simultaneously reads out two 90 -bit CROS words, which use 360 sense lines. The other 40 sense lines are not used in the standard Group 50 CROS, but they are available if needed for RPQ activity.

Figure 12 shows the bit numbering of the sense lines. The top pair of sense lines is bit 0 of the upper word. The next lower pair of sense lines is bit 0 of the lower word. Both the upper and lower words are read out simultaneously. Each sense line is terminated through a resistor to ground.

Figure 13 shows the distribution of a sense line through the planes to the differential sense amplifier. The sense lines through the planes on both sides of a gate are tied together for each bit. The pair of sense lines from each gate is then OR'ed together in the sense amplifier for each bit. Because only one plane has an active drive line for a given ROAR address, the sense amplifier receives only one input signal.

## Physical Package

A CROS plane consists of a "sandwich" composed of the sense line board, a dielectric sheet, and a bit plate. These pieces are held firmly together by pressure plates (Figure 14).

A pressure plate, with a sponge-rubber pad, fits over each group of capacitors in the plane. The
pressure plates are loosely connected to a pressure frame that is bolted to the gate. Pressure adjusting screws in the pressure frame press the pressure plate against the bit plate. Because the sense lines are on a rigidly mounted board, the pressure-plate pressure holds the bit-capacitor "sandwich" firmly together.

Electrical connections to the bit plate are made through pressure connections. Spring-operated pressure bars press the bit plane tabs against the driver line and resistor card tabs (Figure 14).

## SENSE AMPLIFIERS

- Two words are read out and amplified each machine cycle.
- There is a separate sense amplifier for each bit of the two words.
- Each sense amplifier has three stages of amplification.
- The first amplifier stage is a differential amplifier.

The sense amplifiers amplify the voltage difference within a pair of bit sense lines. The first stage of the sense amplifiers (Figures 15 and 16) consists of differential amplifiers, one for gate $C$ sense lines and one for gate D sense lines. Because only one array driver is active for a machine cycle, the sense lines of only one gate carry a signal during a machine cycle. The first stage differential amplifiers amplify the voltage difference within a pair of sense lines and feed the second stage amplifier. The second and third stage amplifier further amplifies the signal and sends the signal to the ROS latches.

The input to the sense amplifier is a pulse which is present on two different input lines. The first stage of the amplifier amplifies the positive or negative difference in voltage between the two input pulses and rejects common mode noise. There are two pairs of inputs and they cannot be used simultaneously.

The differential voltage is further amplified by a shunt feedback stage and a feedback pair. The amplified signal is then applied to the buffer input state of the latch which conditions the signal to be compatible with standard AOI-11 logic.

Standard AOI-11 logic is then used to store the "one" or "zero" until shortly before the next input pulse, at which time the latch is reset.

Capacitors C1 through C11 are used for ac ground or dc blocking only. Capacitors C12 and C13 are used to balance the impedance seen at each input terminal in order to reject the common mode noise. Capacitor C14 is used to extend the band width of the amplifier.

Inductor L1 is used for de biasing and signal isolation from the six-volt power supply.

Resistors R1 through R16 are used for dc biasing. All transistors are biased for class A operation.

## DATA REGISTERS

- ROS latches hold the selected CROS word available for the next machine cycle.
- ROSDR holds the CROS word that controls the present machine cycle.
- 88 ROSDR outgate latches control the decode, parity, and ROAR addressing circuits from 0 ns to 0 ns of a machine cycle.
- 20 ROSDR ingate latches control decode circuits from 130 ns of a machine cycle to 130 ns of the next cycle.
- ROSDR ingate latches allow one CROS word to operate on data during a machine cycle and to store the results in a register during the next machine cycle.

The data registers store the CROS word for use during the machine cycle. The output of the data


FIGURE 11. SENSE LINES


FIGURE 12. SENSE LINE BIT LAYOUT


FIGURE 13. SENSE LINE DISTRIBUTION


FIGURE 14. CROS PLANE PRESSURE MOUNTING ASSEMBLY


FIGURE 15. SENSE AMPLIFIERS


FIGURE 16. SENSE AMPLIFIER SCHEMATIC
registers controls the decode circuits, parity check circuits, and ROAR addressing circuits.

Two CROS words are available at the output of the sense amplifiers, about $3 / 4$ of the way through a machine cycle. The ROAR - B bit position gates one of the two words to the ROS latches (Figure 7).

## ROS Latches

There are 90 ROS latches, one for each bit position of the CROS word. The latches are set by strobing either the upper or lower word sense amplifier outputs (Figure 17). The latches are reset at 130 ns of the machine cycle.

The ROS latches hold the CROS word available to set the ROSDR register at 0 ns of the next machine cycle.

## ROSDR

ROSDR is divided into two sets of registers, ROSDR outgate registers and ROSDR ingate registers. The ROSDR registers hold the CROS word available to the parity, decode, and ROAR addressing circuits. Figure 18 shows the ROSDR registers and their function for a CPU-mode machine cycle.

Note: Machine cycles are either CPU mode or I/O mode; both cycles are under CROS control. I/O mode cycles are machine cycles that use the processing unit circuits to transfer data to or from an I/O channel. A CPU mode cycle is any cycle in which the I/O channels are not using the processing unit circuits.

## Outgate Registers

There are 88 outgate registers, ROSDR positions $00-89$. CROS word positions 24 and 83 are spare positions for future expansion and have no ROSDR register positions.

The ROSDR outgate registers are set from the data in the ROS latches at 0 ns of the machine cycle; the registers remain set until 0 ns of the next cycle. The outgate registers are set in three groups.

Position 0 is used for parity checking and is set each machine cycle.

Positions 6-18 control the address of the next CROS word. On special conditions, such as detecting an invalid address, the address of a fixed routine is inserted into ROAR; an Insert Fixed Add line prevents setting these ROSDR outgate positions.

Positions 1-5 and 19-89 hold the information that is to be decoded to control the system control lines and gates. These positions are prevented from setting on an I/O Break In Cycle, the cycle used to switch from CPU mode to I/O mode. The OFF condition of these ROSDR outgate positions is decoded to cause the $R$ register to be stored in a special position of local storage. Storing the $R$ register allows the I/O mode routine to use the $R$ register without destroying CPU-mode information.

## Ingate Registers

There are 20 ingate register positions, ROSDR positions 19-23, 28-30, and 40-51. The ingate registers are set from the outgate registers at 130 ns of a


FIGURE 17. ROS LATCHES



FIGURE 18. ROSDR
machine cycle. The ingate registers remain set until 130 ns of the next cycle.

The ingate registers allow a CROS word to control some gates during the register set time of the next cycle. For example, one CROS word may contain the micro-instruction: add the $L$ and $R$ registers and store the answer in the $L$ register. This CROS word adds the registers on one machine cycle and stores the sum from the adder-out-bus at register set time of the next cycle.

## CROS WORD DECODE CIRCUITS

- Decode circuits decode ROSDR fields into control lines.
- Some ROSDR fields are decoded differently for CPU mode than for I/O mode.
- Some ROSDR fields are different for CPU mode than for I/O mode.

The CROS word decode circuits combine specific bits from the ROSDR fields with CPU or I/O mode to activate control lines. In some cases the control lines are further combined with the output of latches, such as the M-Byte Counter, to activate more specific control lines.

The division of the ROSDR bit positions into fields is different for CPU mode than for I/O mode. Figure 19 shows the field division for CPU and I/O modes. The function of all the CPU mode fields are shown, but only the functions that differ from CPU mode functions are shown for I/O mode.

The table in Figure 20 shows the micro-orders that control the left mover input, the bit con figuration in the ROSDR LU field that represents the micro-orders, and the resulting control lines and functions.

The left-mover-input decode circuit is a typical example of the CROS word decoding circuits. The left-mover-input decode circuit (Figure 21) uses ROSDR positions 1-3, CPU mode, I/O mode, BAM 0-1 (M-Byte Counter), and BAL 0-1 (L-Byte Counter) to control 13 left-mover-input control lines.

## READ ONLY STORAGE ADDRESS REGISTER (ROAR)

- ROAR supplies the 12 -bit address that selects the next CROS word.
- The 12 ROAR bit positions are $\mathbf{0 - 9}$, A, and B.
- ROAR positions 0-5 are called base address positions.
- ROAR positions 6-9 are called function bits.

ROAR position $A$ is the A-branch bit.

- ROAR position B is the B-branch bit.
- The I/O-backup register saves the CPU-ROAR address during an I/O break-in.
- ROAR addresses come from ROSDR, data flow paths, fixed address generation, or the I/Obackup register.

The Read Only Storage Address Register (ROAR) supplies the address that selects the next CROS word. The present CROS word controls the address sent through the address register. ROAR is composed of a 12 -position address register and three 12position buffer registers.

The address register is not a storage register; instead, the address register is an OR circuit that gates the output of other system-registers to the address-decode circuits (Figure 22).

The three ROAR buffer registers are: an I/Obackup register that saves the last CPU mode address sent to CROS; a current-ROS-address register that saves the address of the current ROSDR word; and a previous-ROS-address register that saves the address of the previous ROSDR word.

On an I/O break-in cycle, the address transferred to the I/O backup register is the address of the CROS word that is prevented from storing in ROSDR. On the last I/O mode cycle, the microprogram word contains the micro-order to transfer the I/O-backup register to ROAR. The address that the backup register sends to ROAR is the address of the CROS word that was prevented from storing in ROSDR on the break-in cycle.

The ROAR bit positions are divided, by the source of their input data, into four groups. These groups are the base-address bits (positions $0-5$ ), the func-tion-branch bits (positions 6-9), the A-branch bit, and the B-branch bit. Figure 23 shows the control circuits for all ROAR positions.

## ROAR Positions 0-5

ROAR positions $0-5$ are called base-address positions. Figure 24 shows a composite logic diagram that represents any base-address position. The inputs to all the base-address positions are similar, except for the fixed-address inserts. The name of the insert lines show which bit positions they affect.

There are eight inputs to the address register OR circuit: data keys, ROSDR, SDR, ROAR buffer, and four fixed address inserts.


FIGURE 19. MICROPROGRAM WORD FIELDS FOR CPU AND I-O MODES

| Micro Order | Bits | Function | Line Name |
| :---: | :---: | :---: | :---: |
|  |  | CPU Mode or 1-0 Mod |  |
| $\begin{aligned} & \mathrm{O}^{\prime} \mathrm{s} \rightarrow \mathrm{U} \\ & R 3 \rightarrow U \end{aligned}$ | $\begin{aligned} & 000 \\ & 010 \end{aligned}$ | Zeros to $U$ $R$ byte 3 to $U$ | $\begin{aligned} & \text { Zero to } U \\ & \text { R24-31 to } U \end{aligned}$ |
|  |  | CPU Mode Only |  |
| $\begin{aligned} & M D, F \rightarrow U \\ & D D \rightarrow U \\ & X T R \rightarrow U \end{aligned}$ | 001 | MD and F registers to $U$ | MD and F to U |
|  | 011 | Direct Data to U | Direct Data Ctrl to Mover |
|  | 100 | XTR:to $U$, reset XTR | XTR to $U$ <br> Int Reg Reset |
| $\begin{aligned} & \text { PSW } \rightarrow U \\ & L / M B \rightarrow U \end{aligned}$ | 101 | PSW (32-39) to U | PSW to U |
|  | 110 | $L$ to $U$ per MB Ctr | L Byte 0 to $U$ |
|  |  | (Which line is active | $L$ Byte 1 to U |
|  |  | is determined by the | $L$ Byte 2 to $U$ |
|  |  | M8 Ctr) | $L$ Byte 3 to U |
| $L / \sim B \rightarrow U$ | 111 | $L$ to $U$ per LB Ctr (Which line is active | $\begin{aligned} & \text { L Byte } 0 \text { to } U \\ & L \text { Byte } 1 \text { to } U \end{aligned}$ |
|  |  | is determined by the LB Ctr) | $L$ Byte 2 to U <br> $L$ Byte 3 to $U$ |
|  |  | I-O Mode Only |  |
| MPX $\rightarrow$ U | 011 | MPX Buffer-In-Bus to $U$ | MPLX Buffer-In-Bus to U |
| LO $\rightarrow$ U | 100 | $L$ byte 0 to U | L Byte 0 to U |
| $\mathrm{LL} \rightarrow \mathrm{U}$ | 101 | $L$ byte 1 to U | L Byte 1 to U |
| $\stackrel{L}{\text { L }}$ - U | 110 | $L$ byte 2 to $U$ | L Byte 2 to $U$ |
| L3 $\rightarrow$ U | 111 | L byte 3 to $U$ | 1 Byte 3 to U |

FIGURE 20. MICRO-ORDER TABLE FOR LEFT MOVER INPUT -ROSDR 1-3



FIGURE 21. DECODE CIRCUITS FOR LEFT MOVER INPUT (ROSDR 1-3)


FIGURE 22. BASIC ROAR DATA FLOW


FIGURE 23. READ ONLY STORAGE ADDRESS REGISTER CONTROLS


Note: This diagram represents any one position of Read Only Storage Address Register positions 0-5. Some special insert lines are not in all positions. The special insert lines are marked for the positions that they control.
ROAR positions 0,1 , and 5 are on ALD page KK301.
ROAR positions 2 and 3 are on ALD page KK311.
ROAR position 4 is on ALD page KK321.

FIGURE 24. READ ONLY STORAGE ADDRESS REGISTER - POSITIONS 0-5

Data-Key Input: The data keys are console switches which allow the CE to insert addresses into ROAR.

ROSDR Input: ROSDR is the normal input to the baseaddress positions. The inhibit-normal-address line prevents sending ROSDR to the address register when micro-orders are gating SDR or ROAR buffer to the address register. The insert-fixed-address line prevents setting ROSDR when either the data-key input or fixed address input is used.

SDR Input: The SDR input gates main storage dataregister positions 19-24 into the base-address positions 0-5. This address path is used for main-stor-age-controlled FLT's (Fault Locating Tests).

I/O Backup Register Input: The I/O-backup input is a micro-order controlled input that supplies the next CPU address following an I/O routine.

Fixed-Address Inputs: The fixed-address circuits supply a fixed address for error traps, I/O break-in, and console switches.

## ROAR Positions 6-9

ROAR positions 6-9 are called function-branch bits. Figure 25 shows a logic diagram that represents any function-branch bit position. The function-branch bit positions can accept bits from the system's data flow path; this allows program data to select one of 16 ROAR addresses.

For example, the instruction-decode routine (I Fetch) uses a function branch on the first four opcode bits to determine the instruction format. The decode routine then uses the last four op-code bits to determine the exact instruction. The ROAR address at the end of the instruction-decode routine is the first word of the instruction routine.

There are nine inputs to the function-branch positions of the address register; data keys, exponentfunction bits, M-register 0-3, M-register 4-7, Fregister, ROSDR, SDR, channel-function bits, and ROAR buffer.

Data-Key Input: The data keys are console switches which allow the CE to insert addresses into ROAR.

Exponent-Function Input: The exponent-function bits are adder-output bits that represent the difference of two exponents. The bits are used to cause a function branch to the proper floating-point shift routine.

M-Register 0-3 Input: Data in M-register 0-3 can be entered as function bits. I Fetch uses this path to enter the first four bits of the op-code.

M-Register 4-7 Input: Data in M-register 4-7 can be entered as function bits. I Fetch uses this path to enter the last four bits of the op-code.

F-Register Input: Data in the F register can be entered as function bits. Hexadecimal multiply uses this function branch. The multiplier is placed in the F register and a function branch is taken to the microprogram routine that multiplies by that value.

ROSDR Input: ROSDR positions 12-15 can be entered into the function-bit positions. ROSDR is used when no function branch or fixed address is desired.

SDR Input: SDR positions 25-28 can be entered as function bits. The SDR entry is used in main-storagecontrolled FLT's.

Channel-Function Bit Input: The channel circuits can insert bits in the function-bit positions. These bits are inserted to select the proper I/O mode routine for the channel operation.

I/O Backup Register Input: The I/O-backup inputs are micro-order controlled inputs that supply the next CPU address following an I/O routine.

## ROAR Position A

The eleventh position of ROAR is called the A-branch position. Figure 26 shows a logic diagram for the A-branch position. The A-branch bit by itself allows a two-way microprogram branch, which is controlled by various system registers and latches. If the Abranch bit is used in conjunction with a function branch, the microprogram can branch to any one of 32 addresses.

There are six groups of inputs to the A-branch address-register position: tests controlled by ROSDR 72-77, tests controlled by ROSDR 16-18, SDR, data keys, ROAR buffer, and fixed-address inserts.

Tests Controlled by ROSDR 72-77: These tests are the inputs controlled by the $\mathrm{A} \mathrm{Br} \mathrm{Ctrl} 01-63$ lines. The A Br Ctrl lines are the binary decoded output of ROSDR 72-77. In the ALD's this line is really two lines, an $X$ line and a $Y$ line. The $X$ and $Y$ lines are formed by octal decoding the six bits of the field.

Tests Controlled by ROSDR 16-18: These tests force the A-branch bit to a " 1 " state by testing the Bbranch bit. This test can be used in conjunction with the tests controlled by ROSDR 72-77. If the conditions are satisfied for either test, the result is an A-branch bit.

Note: This A-branch test should not be used in conjunction with the two immediate B -branch tests, the adder carry test and the adder sum position 0 equals zero test. These two B-branch tests occur too late in the machine cycle for reliable A-branch bit operation if this test is used.

SDR Input: SDR position 29 can be entered into the A-branch bit position. The SDR entry is used in main-storage-controlled FLT's.

Data-Key Input: The data keys are console switches which allow the CE to insert addresses into ROAR.

I/O Backup Register Input: The I/O-backup inputs are micro-order controlled inputs that supply the next CPU address following an I/O routine. No A-branch test micro-orders should be used in conjunction with the micro-order to gate the ROAR buffer to ROAR.

Fixed-Address Input: The fixed-address circuits supply a fixed address for error traps, I/O break-in, and console switches.

## $\underline{\text { ROAR Position B }}$

The twelfth position of ROAR is the B-branch position. Figure 27 shows the logic of the B-branch position. The B-branch bit by itself allows the system data to control a two-way microprogram branch. If the Bbranch bit is used in conjunction with the A-branch bit and the function-branch bits, the microprogram can branch to any one of 64 addresses.

The B-branch position is not used to select an array driver. Instead, it is used to gate one of the two CROS words read out by the ROAR address into the ROS latches. Because the B-branch bit is not used to read out CROS, it can be set later in the machine cycle than the rest of the ROAR address.

The A-branch tests and most of the B-branch tests are made on conditions at the start of the machine cycle. However, the B-branch has two tests that are made late in the machine cycle, branch-on adder carry and branch-on adder pos 0 sum equal zero. These two tests are made just before the CROS output is gated into the ROS latches. To speed up the upperlower gating circuits, the B-branch position has two output circuits, one for the no-bit condition and one for the bit condition.

There are six groups of inputs to the B-branch address-register position; tests controlled by ROSDR $78-82$, tests controlled by ROSDR $16-18$, tests controlled by ROSDR 72-77, data keys, SDR, and ROAR buffer.

## Tests Controlled by ROSDR 78-82: These tests are

 the inputs controlled by $\mathrm{B} \mathrm{Br} \mathrm{Ctrl} 01-31$ lines. TheB Br Ctrl lines are the binary decoded outputs of ROSDR 78-82. In the ALD's these lines are really AND'ed $X$ and $Y$ lines. The $X$ and $Y$ lines are formed by octal decoding the five bits of the field.

Note: If ROSDR 72-77 contains a test that affects the B branch bit, ROSDR 78-82 must be all zeros (no test).

Tests Controlled by ROSDR 16-18: These tests force the B branch bit to a " 1 " state, by testing the Abranch bit. These tests can be used in conjunction with other ROSDR controlled tests; if the conditions are satisfied for any test, the result is a B-branch bit.

Tests Controlled by ROSDR 72-77: There are four Abranch control tests that affect the B-branch bit. These four A-branch control tests allow one microorder to control a four way branch. ROSDR 78-82 must be all zeros if these tests are used.

A Br Ctrl 35 sets the A branch bit with edit stat 1 ; it sets the $B$ branch bit with edit stat 2 .

A Br Ctrl 49 sets the A branch bit with mover position 6; it sets the $B$ branch bit with mover position 7.

A Br Ctrl 56 sets the A branch bit with either an exception branch stat, or with no-bit in instruction counter position 30. A Br Ctrl 56 sets the $B$ branch bit with either refetch stat and an instruction counter position 30 bit, or with an exception branch stat.

A Br Ctrl 58 sets the A branch bit with either a timer or an external channel signal; it sets the $B$ branch bit with a channel inter rupt signal.

Data Key Input: The data keys are console switches which allow the CE to insert addresses into ROAR.

SDR Input: SDR position 30 can be entered into the $B$ branch bit position. The SDR entry is used in main-storage-controlled FLT's.

I/O Backup Register Input: The I/O-backup inputs are micro-order controlled inputs that supply the next CPU address following an I/O routine. No Bbranch test micro-order should be used in conjunction with the micro-order to gate the ROAR buffer to ROAR.

## DRIVER SELECTION

- ROAR positions 5-9 are decoded into 1 of 22 select lines.
- ROAR positions 0-4 and A are decoded into 1 of 64 strobed drive lines.


Note: This diagram represents any one position of Read Only Storage Address Register positions 6-9 (FCN Bits 0-3)
FCN Bit 0 is on ALD page KKO1
FCN Bit 1 is on ALD page KK021
FCN Bit 2 is on ALD page KK031
FCN Bit 3 is on ALD page KK041

FIGURE 25. READ ONLY STORAGE ADDRESS REGISTER - POSITIONS 6-9


FIGURE 26. READ ONLY STORAGE ADDRESS REGISTER - POSITION A


- One select line and one strobed drive line selects 1 of 1,408 array drive lines.

The driver selection circuits decode the address in ROAR positions $1-$ A to select one of 1,408 CROS array drive lines. The ROAR address is decoded into a select line and a strobed drive line. The select and strobed drive lines are then AND'ed to select one array drive line.

## Select Lines

Select lines are activated by decoding the base-ad-dress-5 position and the four function-branch positions of ROAR (Figure 28). Although these five ROAR bit positions can be decoded 32 different ways, only the first 22 combinations are considered valid addresses. The other ten combinations are not tested. If (by error) the bit combination for a 31 is entered into these ROAR positions, the decode circuit will treat it as a bit combination for a 15 . Select line 15 will be activated.

## Strobed Drive Lines

A ROAR address selects one of 64 strobed drive lines by decoding the base address $0-4$ and the $A$ branch positions (Figure 29). The decoded address is AND'ed with driver strobe to send a timed signal to the array drivers. Each strobed drive line controls the array drivers for one CROS quarter plane.

Base addresses 0-2 are AND'ed to select one of seven first drive lines. The first drive lines are AND'ed with base addresses $3-4$ to select one of 32 second drive lines. The second drive lines are AND'ed with the A branch bit and driver strobe to select one of 64 strobed drive lines.

Array Drivers
There are 1,408 array drivers. Each array driver is a simple AND switch that AND's one of the 64 drive
lines with one of the 22 select lines (Figure 30). The AND circuits are single transistors; the drive lines gate the emitters while the select lines control the bases. Voltage is supplied to the collectors through the array drive-line-terminating resistors.

Figure 31 shows the layout of the drive lines as they enter a CROS plane.

## CROS WORD PARITY CIRCUITS

- The CROS word is parity checked in three groups, ROSDR 0-30, ROSDR 31-55, and ROSDR 56-89.
- The first bit of each group is a parity check bit.
- Each group must have odd parity to be valid.
- ROSDR 0-30 is not checked on an "Insert Fixed Address" cycle.
- ROSDR 0-89 is not checked on a "I/O Break In" cycle.

The CROS word in ROSDR is parity checked in three groups (Figure 32). Each group contains its own parity check bit and must total an odd number of bits to result in correct parity.

ROSDR $0-30$ has a special circuit that forces correct parity on any cycle that inserts a fixed address into ROAR. This circuit is necessary because ROSDR 6-18 is prevented from storing CROS bits when the insert fixed address line is active.

ROSDR 0-89 is not parity checked on a "I/O Break In" cycle. Only CROS word position 0 is allowed to store in ROSDR on a break-in cycle; therefore, the ROSDR word would always result in a parity error if it is checked on a break-in cycle.


| Select <br> Lines | ROAR Positions |  |  |  |  |
| :---: | :---: | :---: | :---: | :---: | :---: |
|  | 5 | 6 | 7 | 8 | 9 |
| 0 | 0 | 0 | 0 | 0 | 0 |
| 1 | 0 | 0 | 0 | 0 | 1 |
| 2 | 0 | 0 | 0 | 1 | 0 |
| 3 | 0 | 0 | 0 | 1 | 1 |
| 4 | 0 | 0 | 1 | 0 | 0 |
| 5 | 0 | 0 | 1 | 0 | 1 |
| 6 | - | 0 | 1 | 1 | 0 |
| 7 | - | 0 | 1 | 1 | 1 |
| 8 | - | 1 | 0 | 0 | 0 |
| 9 | - | 1 | 0 | 0 | 1 |
| 10 | - | 1 | 0 | 1 | 0 |
| 11 | - | 1 | 0 | 1 | 1 |
| 12 | - | 1 | 1 | 0 | 0 |
| 13 | - | 1 | 1 | 0 | 1 |
| 14 | - | 1 | 1 | 1 | 0 |
| 15 | - | 1 | 1 | 1 | 1 |
| 16 | 1 | - | 0 | 0 | 0 |
| 17 | 1 | - | 0 | 0 | 1 |
| 18 | 1 | - | 0 | 1 | 0 |
| 19 | 1 | - | 0 | 1 | 1 |
| 20 | 1 | - | 1 | 0 | 0 |
| 21 | 1 | - | 1 | 0 | 1 |

Select Lines 0-5 are decoded from ROAR Pos $5,6,7,8$, and 9 .

Select Lines 6-15 are decoded from ROAR Pos $6,7,8$, and 9 .

Select Lines 16-21 are decoded from ROAR Pos $5,7,8$, and 9 .

FIGURE 28. BINARY DECODE OF ROAR TO SELECT LINES


FIGURE 29. BINARY DECODE OF ROAR TO I OF 64 DRIVE LINES


FIGURE 30. SELECTION OF ONE OF 1408 ARRAY DRIVERS



FIGURE 32. PARITY CHECKING ROSDR

- Fixed microprogram routines control the system operations.

A CROS word is read out and stored in ROSDR every machine cycle. This CROS word, the microprogram word, controls the processing unit's gates and control lines during the machine cycle that the word is stored in ROSDR. The address of the next microprogram word is gated into ROAR from ROSDR, or data flow paths under ROSDR control, or from fixed address insertion circuits.

A series of microprogram words cause the system to perform a specific routine. When the machine is manufactured, a microprogrammer specifies which bits each microprogram word must contain to make the routines work. The microprogrammer's routines are used to make the CROS bit plates and the CAS logic diagrams.

## MICROPROGRAM INSTRUCTION WORD

- Fields within the microprogram word control the address of the next microprogram word.
- Fields within the microprogram word control the gates and control lines for one machine cycle.

A microprogram word is one CROS word. To control the system, the microprogram word must be read into ROSDR.

The microprogram word is divided into control fields. The control fields are used to address the next CROS word and to control the system's gates and control lines.

Control Fields
The control fields and their functions are shown in Figure 19). The bit combination within a control field is decoded into a micro-order. Only one microorder is possible from a control field for any one microprogram word. However, one micro-order can control a number of control lines and gates.

## Micro-Orders

A micro-order represents a specific bit combination within a control field. The microprogrammer writes the microprogram routines by specifying the microorders for each microprogram word. The CAS logic diagram is a listing of the micro-orders specified by the microprogrammer for each microprogram word. System/360 Model 50 Diagrams Manual, Z22-2833, shows a listing of all the micro-orders and their functions.

## CAS Logic Diagrams (CLD's)

The CAS diagrams are control automation system diagrams that document the microprogram routines. Each block on the CAS diagrams represents one microprogram word. The micro-orders that were specified by the microprogrammer are shown in the CAS block. Control fields that have no micro-order specified by the microprogrammer are automatically set to a predetermined bit configuration when the bit plate is manufactured. These automatically inserted bits usually represent a no-operation condition for the control field. However, some control fields are set to a pertinent micro-order when no other micro-order has been specified. These control fields are shown in Figure 34.

Figure 35 shows the basic layout of a CAS logic diagram block with each line labeled as to its purpose. Also shown in Figure 34 is a list of special character definitions as used in the CAS logic diagram block.

Figure 36 shows, specifically, the control field mnemonics that may appear in any given print position of the CAS logic diagram block.

A typical CAS logic diagram (word XTTD0) is shown in Figure 33. Beginning at the top:
B Branch Bit
A Branch Bir
Function Branch Bits 7

| $110100 \square 134$ |  |  |
| :---: | :---: | :---: |
| E | 0001 |  |
| A | $\mathrm{M} 23+\mathrm{L}-\mathrm{L}$ |  |
| B | $M L B=G$ |  |
| L | $L \rightarrow L S$ |  |
| L | WS $\rightarrow$ LSA |  |
| S | $1 A R+2 \rightarrow A$ |  |
| C | $E=547$ |  |
| C | $\begin{aligned} & 0 \rightarrow L B \\ & A \Omega(B=1) \rightarrow A \end{aligned}$ |  |
| R | IA30 | 57 |

FIGUN: 33. TYPICAL CAS DIAGRAM BLOCK (WORD XTTDO)
Item E - Is the bit configuration of the emit field.
Item A - This micro-order true adds the right half of the M register to the L register and stores the result in the $L$ register.

Item B - The micro-order gates the byte of the M register specified by the $L$ byte counter through the mover to the $G$ register.

Item L (1) - Is a micro-order which causes the sum that was just stored in the $L$ register to be stored in local storage.

| Field Bits | Micro- <br> Order | Field Function | Micro-Order Function |
| :---: | :---: | :---: | :---: |
| $T C=1$ | + | True or Complement Add | True Add |
| $A D=1$ | BLANK | Adder Function | Binary Add, No Carry Saved |
| $A L=0$ | BLANK | Adder Latch Input | Shift Zero |
| $U L=1$ | $\mathrm{UL} \rightarrow \mathrm{WL}$ | Mover Action Left Digit | U 0-3 to W 0-3 |
| $U R=1$ | $U R \rightarrow W R$ | Mover Action Right Digit | U 4-7 to W 4-7 |
| $U P=2$ | -1 | Byte Counter Function Control | Count the selected counter down |
| $W S=4$ | $F N, J \rightarrow L S A$ | Local Store Addressing (CPU) | Gate LSFN and J to LSAR |
| $C S=0$ | 2,3 | Local Store Sector (1-O) | Select the sector for the L and $R$ backup area |
| $S A=0$ | $0 \rightarrow$ LSA | Local Store Addressing (1-O) | Gate the I-O function + zero to LSAR <br> Note: Used in conjunction with $C S=0$, this micro-order addresses the R register backup word |
| $M G=3$ | $\mathrm{BFRI} \rightarrow \mathrm{BIB}$ | Multiplex Gate Control (I-O) | Gate Buffer 1 to MXBIB |

FIGURE 34. NON-NOP AUTOMATIC MICRO-ORDERS


Special Character Definitions

| + | True Add or Positive | $\forall$ | Is "Exclusive OR'ed" with |
| :---: | :---: | :---: | :---: |
| - | Complement Add or Negative | $\Omega$ | Is OR'ed with |
| $=$ | Is Equal | 1 | Or (non-logical) |
| $\neq$ | Is Unequal | $<$ | Is less than |
| $\rightarrow$ | Is Set Into (Destructive Read-In is implied) | $>$ | Is greater than |
| - | Is AND'ed with (logical) | 7 | Not (Boolean-used as the not function on CLD's) |
| , | And ( non-logical) | : | Is compared to |
| ? | Indeterminate function ( hardware controlled) |  |  |

* Any Selector Bit Equals:

| 0 Branch Bit | 0 |
| :--- | :--- |
| 1 | Branch Bit |
| Test For Branch Bit | 1 |
| No Test For Branch Bit <br> (don't care) | $\times$ |

FIGURE 35. CAS DIAGRAM BLOCK (BASIC LAYOUT)


FIGURE 36. CAS DIAGRAM BLOCK -- SPECIFIC LAYOUTS



Item L (2) - This micro-order specifies the area of local storage to use (working-storage-one).

Item $S$ - Is the micro-order which causes the IAR to be incremented by two (refetch is off) and sent to SAR.

Item C (1) - This micro-order causes general purpose stats $4-7$ to be set from the emit field (in this case, stats 4-6 are set off, and stat 7 is set on).

Item C (2)- This micro-order sets the L byte counter to zero.

Note: Registers are set at the beginning of the next machine cycle. Therefore, setting the $L$ byte counter to zero does not affect which byte of the M register is gated out.

Item R (1) - Is the micro-order which forces the Abranch bit to one if the B-branch bit is turned on by its test.

Items R (2) - This micro-order sets the A-branch bit to one if IAR (30) contains a one.

## INSTRUCTION-FETCH ROUTINE

- I-Fetch reads and decodes the program instructions.
- Instructions start on halfword boundaries.
- The op-buffer saves the odd instruction-halfword of a storage read.
- The refetch latch records the possibility that the data in the op-buffer is invalid because of the execution of the last instruction.

The instruction fetch routine (I-fetch) reads the instruction from storage, decodes the instruction, and branches to the proper execute routine.

The instruction address register (IAR) contains the address of the first byte of the instruction. Instructions can start on a word boundary (IAR holds an even halfword address) or on a halfword boundary (IAR holds an odd halfword address). Instructions can be a halfword, word, or three halfwords long.

The last halfword of many instructions will be the first halfword of a storage word; the last half of the storage word is the first halfword of the next instruction. To save machine cycles, the halfword that belongs to the next instruction is stored in a reserved local storage position called the op buffer.

A refetch latch is turned on if the execution of the present instruction could possibly store data in the
storage address positions of the next instruction. If the refetch latch is on, I-fetch will not use the halfword stored in the op-buffer. Instead, I-fetch reads the entire instruction from storage.

Figure 37 shows the instruction formats and the source of the instruction halfwords for all conditions.

The instruction routine is divided into two sections, first level I-fetch and second level I-fetch. First level I-fetch determines the instruction format. Second level I-fetch determines the specific operation to be performed.

## First Level I-Fetch

- Stores the first two instruction halfwords in the M register (one halfword for RR format).
- Sets the instruction length counter (ILC).
- Stores the data from the local storage address specified by the $B$ field in the $L$ register.
- Decodes the instruction format from the first four bits of the op-code.

Figure 38 shows a logic flow chart of first level Ifetch. A more detailed flow chart of first level Ifetch is in System/360 Model 50 Diagrams Manual, Form Z22-2833.

The data flow in first level I-fetch depends on three conditions: the IAR address, the refetch latch, and the format of the instruction.

The IAR address determines the source of the first instruction halfword. If IAR contains an even address, the storage word is read out and stored in both the M register and the op buffer. If IAR contains an odd address, the refetch latch determines the source of the first instruction halfword.

The refetch latch determines whether or not the halfword stored in the op buffer is valid. If the refetch latch is on, the halfword may be invalid; the halfword is reread from storage and stored in the left half of the $M$ register. If the refetch latch is off, the halfword from the op buffer is stored in the left half of the $M$ register.

The instruction length in the first halfword is checked to determine if the instruction is in $R R$ format. If the instruction is in RR format, the M register contains the entire instruction. If the instruction is not in RR format, the second instruction halfword is read from storage. The left half of the storage word (second instruction halfword) is stored in the right half of the M register, and the entire storage word is stored in the op buffer to save the odd halfword.


FIGURE 37. INSTRUCTION FORMATS AND SOURCE OF INSTRUCTION HALFWORDS


FIGURE 38. FIRST LEVEL I-FETCH

After the first two instruction halfwords are stored in the $M$ register, the address specified by the $B-$ field is read from local storage and stored in the $L$ register. A function branch is taken, on the first four bits of the op code, to the proper format second level I-fetch.

## Second Level I-Fetch

- Second level I-fetch differs for each format.
- Second level I-fetch fetches the third instruction halfword for SS formats.
- Second level I-fetch prepares the data addresses.
- Second level I-fetch saves the IAR address if the format can contain a branch and link instruction code.
- Second level I-fetch branches to the proper microprogram routine to execute the instruction.
- Unassigned op-code combinations cause a branch to a program trap routine.

Second level I-fetch completes the decoding of the instruction, stores the IAR address if the instruction format could result in a branch instruction, and branches to the proper execute microprogram.

Figures 39 and 40 show the second level I-fetch flow paths for all valid and invalid op-codes (invalid op-codes are the unassigned configurations of the eight-bit op-code field).

RR Formats: The RR0 format ( 0 X codes) stores the contents of the general purpose register specified by the $R 2$ field in the $R$-register. The contents of IAR are stored in the H -register to save the next instruction address if this instruction results in a branch operation.
$R R$ formats $1-3$ ( $1 \mathrm{X}-3 \mathrm{X}$ codes) store the contents of the general purpose register specified by the R2 field in the L-register.

RR formats $2-3$ ( $2 \mathrm{X}-3 \mathrm{X}$ codes) set the carry stat as a signal to the floating-point routine whether to operate in floating-point long or floating-point short mode.

RX Formats: The RX4 format (4X codes) computes the effective address by adding the contents of the general purpose registers specified by the B and X fields to the displacement field, and stores the result in the L-register. The general purpose register specified by the R1 field is stored in the R-register. The contents of IAR are stored in the H-register to
save the next instruction address if this instruction results in a branch operation.

The RX5 format ( 5 X codes) computes the effective address by adding the contents of the general purpose registers specified by the $B$ and $X$ fields to the contents of the displacement field, and stores the result in the R-register. The contents of the general purpose register specified by the R1 field are stored in the L-register.

RX formats 6-7 ( $6 \mathrm{X}-7 \mathrm{X}$ codes) compute the effective address by adding the contents of the general purpose registers specified by the $B$ and $X$ fields to the contents of the displacement field, and stores the result in the R-register and WS1 of local storage. General purpose stat 3 is set as a signal to the float-ing-point routine whether to operate in floating-point long or short mode.

RS/SI Formats: The RS8 formats ( 8 X codes) compute the effective address by adding the contents of the general purpose register specified by the B-field to the contents of the displacement field, and store the result in the R -register. The contents of the general purpose register specified by the R1 field are stored in the L-register.

The RS9 format ( 9 X codes) computes the effective address by adding the contents of the general purpose register specified by the B -field to the contents of the displacement field, and stores the result in the Rregister and in WS1 of local storage.

SS Formats: The SSD format (DX codes) computes the effective operand 1 address ( $\mathrm{B} 1+\mathrm{D} 1$ ) and stores the result in the R -register and in WS 1 of local storage. The L1 and L2 fields are stored in the G-register. The third halfword is read into the M-register (positions $16-31$ ), and the effective operand 2 address is computed and stored in the L-register and in WS2 of local storage. The byte position of the operand 1 address is stored in the MB counter to use in locating the first data-byte-position in the operand 1 word.

The SSF format (FX codes) computes the effective operand 1 address ( $B 1+\mathrm{D} 1$ ) and stores the result in the L-register and in WS9 of local storage. The L1 and L2 fields are stored in the G-register. The third halfword is read into the right half of the M-register, and the operand 2 effective address is computed and stored in WSA of local storage. The low-order address of the operand 1 field is computed and stored in WS1; the byte position of the low-order address is stored in the MB counter. The low-order address of the operand 2 field is computed and stored in WS2; the byte positon of the low order address is stored in the LB counter.


Note: The function branch decodes Op -Code bits 4-7 and branches to the proper routine for the Op -Code.
Some combinations of the eight bit Op-Code are invalid. The invalid codes are:

Valid
Invalid

| Valid | Invalid |
| :--- | :--- |
| $04-0 \mathrm{~A}$ | $00-03,0 B-0 \mathrm{~F}$ |
| $10-1 \mathrm{~F}$ | None |
| $20-24,2 \overline{8}-2 \mathrm{~F}$ | $25-27$ |
| $30-34,38-3 \mathrm{~F}$ | $35-37$ |
| $40-4 \mathrm{C}, 4 \mathrm{E}-4 \mathrm{~F}$ | 4 D |
| $50,54-5 \mathrm{~F}$ | $51-53$ |
| $60,68-6 \mathrm{~F}$ | $61-67$ |
| $70,78-7 \mathrm{~F}$ | $71-77$ |

FIGURE 39. SECOND LEVEL I-FETCH RR AND RX FORMATS


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